

KSA1370

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Crt Display, Video Output

- High Voltage
- Low Reverse Transfer Capacitance : $C_{re} = 1.7\text{pF}$



PNP Epitaxial Silicon Trnsistor

Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------|-----------------------------|-----------|------------------|
| V_{CBO} | Collector-Base Voltage | -200 | V |
| V_{CEO} | Collector-Emitter Voltage | -200 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I_C | Collector Current (DC) | -100 | mA |
| I_{CP} | Collector Current (Pulse) | -200 | mA |
| P_C | Collector Power Dissipation | 1.0 | W |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^\circ\text{C}$ |

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|----------------------|--------------------------------------|--|------|------|------|---------------|
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = -10\mu\text{A}, I_E = 0$ | -200 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -1\text{mA}, I_B = 0$ | -200 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = -10\mu\text{A}, I_C = 0$ | -5 | | | V |
| I_{CBO} | Collector Cut-off Current | $V_{CB} = -150\text{V}, I_E = 0$ | | | -0.1 | μA |
| I_{EBO} | Emitter Cut-off Current | $V_{EB} = -4\text{V}, I_C = 0$ | | | -0.1 | μA |
| h_{FE} | DC Current Gain | $V_{CE} = -10\text{V}, I_C = -10\text{mA}$ | 100 | | 320 | |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = -20\text{mA}, I_B = -2\text{mA}$ | | | -0.6 | V |
| $V_{BE}(\text{on})$ | Base-Emitter On Voltage | $I_C = -20\text{mA}, I_B = -2\text{mA}$ | | | -1.0 | V |
| f_T | Current Gain Bandwidth Product | $V_{CE} = -30\text{V}, I_C = -10\text{mA}$ | | 150 | | MHz |
| C_{ob} | Output Capacitance | $V_{CB} = -30\text{V}, f = 1\text{MHz}$ | | 2.6 | | pF |
| C_{re} | Reverse Transfer Capacitance | $V_{CB} = -30\text{V}, f = 1\text{MHz}$ | | 1.7 | | pF |

Typical Characteristics

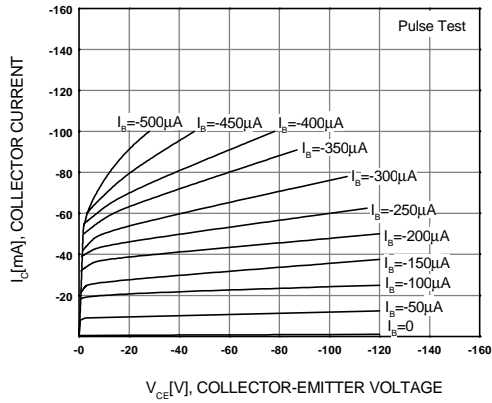


Figure 1. Static Characteristic

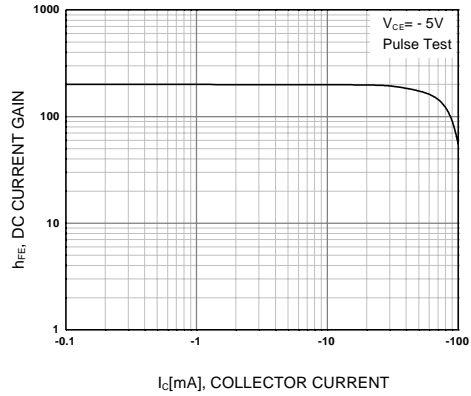


Figure 2. DC current Gain

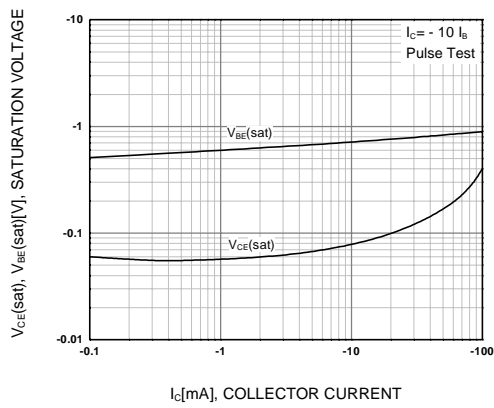


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

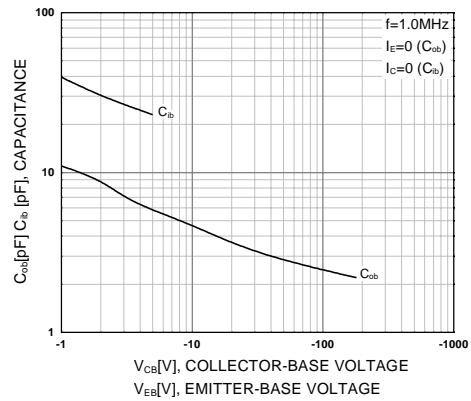


Figure 4. Collector Output Capacitance

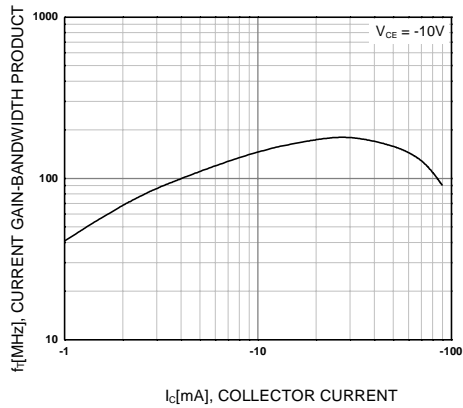


Figure 5. Current Gain Bandwidth Product

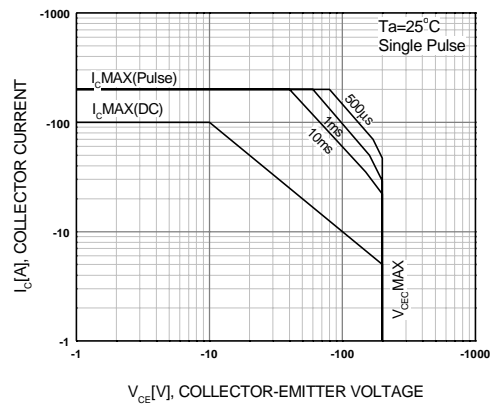


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

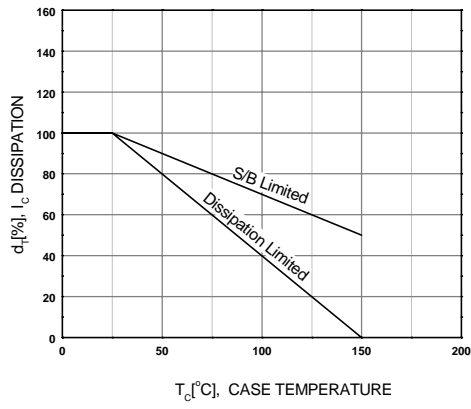


Figure 7. Derating Curve of Safe Operating Areas

Package Dimensions

TO-92L



Dimensions in Millimeters

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